



#### Digital Barometer

#### **Key parameters**

Pressure range: 300 ... 2000hPa

 Package: 4-pin LGA metal-lid Footprint: 4.5 × 4.5mm<sup>2</sup>

Height: 3.5mm

Relative accuracy: ±0.03 hPa(±0.25m)

• Absolute accuracy: typ. ±1.5hPa

 Temperature coefficient offset: 1.5 Pa/K, (12.6 cm/K)

Digital interface: I<sup>2</sup>C

 Current consumption: 3.5µA @1Hz sampling rate

Temperature range: -40~+85°C

RoHs compliant, halogen-free

#### Typical applications

- Barometer and altimeter for portable devices
- Indoor and outdoor navigation
- Weather station equipment
- Sport watches
- Flying toys

#### **Technical advantages**

- Wide compensate temperature
  -40~+80°C
- Small package, height only 3.3mm
- Excellent performance and cost

#### **Brief Description**

WF5805F is a high precision barometer and altimeter especially designed for consumer applications. It measures the pressure based on piezo-resistive MEMS pressure sensor.

The ultra-low power, low voltage electronics of the WF5805F is optimized for use in mobile phones, smart watches, PDAs. GPS navigation devices outdoor equipment. The sensor module is housed in a compact 8-pin metal-lid LGA package with a footprint of only 4.5 × 4.5 mm<sup>2</sup> and 3.5 mm package height. Its small dimensions and its low power consumption allow the implementation in battery driven devices. With a low altitude noise of merely 0.08m and very low offset temperature coefficient(TCO), the WF5805F offers superior performance and cost are perfectly suitable for applications like flying toys and sport watches. The I2C/SPI interface allows for easy system integration with a microcontroller.



# 1 Specification

VDD = 3.3V, T= $25^{\circ}$ C, unless otherwise noted.

Table 1 Parameter specification

Parameter	Symbol	Condition	Min	Тур	Max	Units
Operating temperature	_	operational	-40	25	+85	°C
range	T <sub>-A</sub>	full accuracy	0		65	
Operating pressure	Р	full accuracy	300		2000	hPa
range	r	Tull accuracy	300		2000	IIPa
Sensor supply voltage	V <sub>DD</sub>		1.8		3.6	V
Interface supply voltage	V <sub>DDIO</sub> .		1.8		3.6	V
Supply current	I <sub>DD</sub> , LP	1Hz, ultra low power		3.4		μΑ
Peak current	I. <sub>peak</sub> .	during pressure measurement		1950		μΑ
Current at temperature measurement	I. <sub>DDT</sub>			900		μA
Sleep current	I <sub>DDSL</sub>	25°C		0.1	0.3	μΑ
Relative accuracy		700900hPa		±0.03		hPa
VDD=3.3V	A <sub>rel</sub>	2540°C		±0.25		m
Offset temperature	тсо	900hPa		±1.5		Pa/K
coefficient	100	2540°C		±12.6		cm/K
		3002000hPa		±2.0		hPa
Absolute accuracy		-200°C 6080 °C				
pressure		3001100hPa 060℃		±1.5		hPa
Resolution of output data in ultra high		Pressure		0.025		Pa
resolution mode		Temperature		0.01		°C
	V	Full bandwidth, ultra high		1		Pa
Naiss is sussesses	V.P,full	resolution		8		cm
Noise in pressure		Lowest bandwidth, ultra		0.2		Pa
V <sub>P</sub> , filtered		high resolution		1.7		cm
Absolute accuracy	$A^{T}$	<b>@25</b> ℃		±0.5		°C
temperature	A.	0+65℃		±1.0		°C
PSRR (DC)	PSSR	Full V <sub>DD</sub> range			±0.005	Pa/mV
Long term stability	ΔPstab	12 months		TBD		hPa
Solder drifts			-0.5		+2	hPa
Possible sampling rate	f <sub>sample</sub>		587	649	TBD	Hz



# 2 Absolute maximum ratings

Table 2 Absolute maximum ratings

Parameter	Symbol	Condition	Min	Max	Units
Supply voltage	V <sub>DD</sub>		-0.3	+3.6	V
Voltage at all IO Pins	V <sub>DDIO</sub>	all pins	-0.3	V <sub>DD</sub> +0.3	٧
Overpressure	Р		0	10,000	hPa
Storage temperature	T <sub>STOR</sub>		-45	+85	°C
ESD rating	ESD	НВМ		±2	kV



## 3 Operation

### 3.1 Brief description

The WF5805F is designed to be connected directly to an external microcontroller of a mobile device via the I<sup>2</sup>C. The pressure and temperature data has to be compensated by the calibration data of the on-chip Non-Volatile Memory (NVM) which is individually factory calibrated for each device.

### 3.2 Function description

The WF5805F consists of a piezo-resistive micro-machined pressure sensor, an analog to digital converter and a control unit with Non-Volatile Memory (NVM) and a serial  $I^2C$  interface. The WF5805F delivers the uncompensated values of the pressure and the temperature. The individual calibration data are stored in NVM. This is used to compensate sensitivity, offset, temperature dependence and other parameters of the sensor.

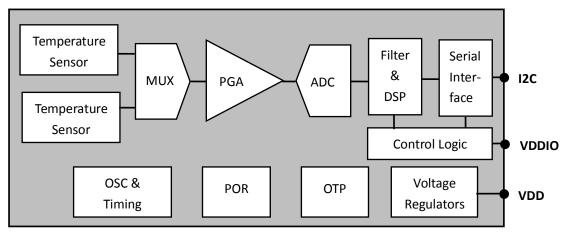


Figure 1 Block diagram of WF5805F

## 3.3 Measurement of pressure and temperature

The microcontroller sends I<sup>2</sup>C write register to start a pressure or temperature measurement. After converting time or checking status via the I<sup>2</sup>C, the result value (raw pressure data and raw temperature data) can be read via the I<sup>2</sup>C interface. For pressure and temperature calibration calculation in microcontroller, the calibration data in NVM has to be used. The constants can be read out from the WF5805F's NVM via the I<sup>2</sup>C interface at software initialization.



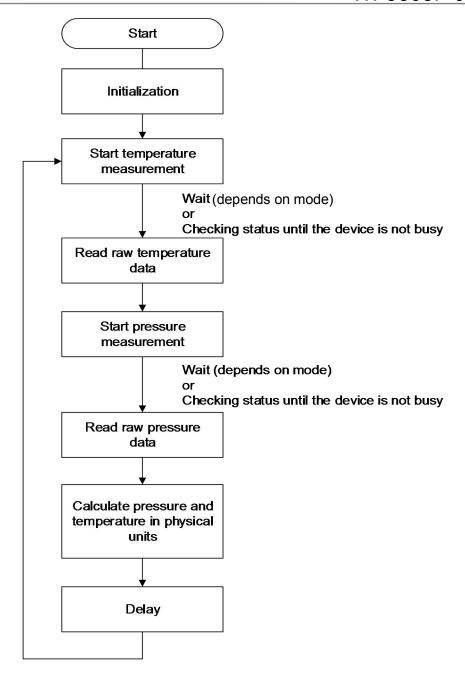


Figure 2 Measurement flow of WF5805F

### 3.4 Timing of the measurements

The output data rate (ODR) of the measurements is controlled by the external microcontroller. A single measurement is performed according to the received I<sup>2</sup>C register value. When the measurement is finished, the sensor returns to sleep mode and the measurement results can be obtained via I<sup>2</sup>C interface.

The ODR can be increased to more than 500 samples per second for dynamic measurement. For application with high ODR, constant  $t_{\text{delay}}$  is recommended as the



self-heating of the pressure sensor and heat dissipation are in the balance if sampling rate is constant, which helps reducing the noise caused by irregular heat exchange between the sensor and the ambient environment. The recommended working timing diagram is shown in Figure 3.

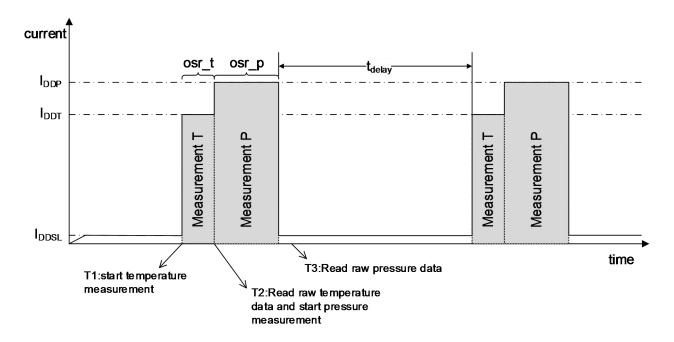


Figure 3 Recommended working timing diagram

For applications which require low ODR or host-based synchronization, the  $t_{\text{delay}}$  can be set with any value larger than 0.5ms. The optimum compromise between power consumption, speed and resolution can be selected.

#### 3.5 Measurement time

The temperature and pressure measurement time depends on oversampling setting osr\_t and osr\_p. The following table shows the typical and maximum measurement time based on selected oversampling setting. The minimum achievable frequency is determined by the maximum measurement time.

OSR setting	Measurement	Measurement
(Single pressure or	time [ms]	rate [Hz]
temperature)	Тур	Тур
256x	1.54	649
512x	1.86	537
1024x	2.5	400
2048x	3.78	264

Table 3 Measurement time

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4096x	6.34	157
8192x	11.46	87
16384x	21.7	46
32768x	42.18	23

## 3.6 Output compensation

The WF5805F output consists of the ADC output values include raw temperature and pressure data. Due to different characteristic of each sensing element, the actual pressure and temperature must be calculated using a set of calibration coefficients. These coefficients are individually factory calibrated and stored in the NVM. The NVM is organized with 16-bit data type.

### 3.7 Compensation formula

The ODR and OSR can be selected by selected by the oversampling\_setting in the C code. Using the driver C code provided by WF Tech. Inc. is strongly recommended. Please contact with WF Tech. Inc. for details.



## 4 Registers

All the WF5805F registers can be departed into normal registers and OTP registers. The normal registers are used to send a conversion command to the WF5805F, read back the conversion data and perform the OTP blowing. The OTP registers are used to store the configurations and calibration coefficients for the WF5805F, whose default values can be programmed by the inside OTP banks.

### 4.1 Normal Registers

The WF5805F is designed to be connected directly to an external microcontroller of a mobile device via the I<sup>2</sup>C . The pressure and temperature data has to be compensated by the calibration data of the on-chip Non-Volatile Memory (NVM) which is individually factory calibrated for each device.

Description R/W Bit7 Bit6 Bit5 Bit4 Bit2 Bit1 Bit0 **Default** Addr Bit3 0x00 SPI\_Ctrl RW LSB\_fi Softre Softre LSB SDO 0x00 SDO active rst set set first active 0x01 Part ID R PartID<7:0> 0x00 0x02 Error\_code<3:0> 1'b0 **DRDY Status** 0x06 DATA MSB Data out < 23:16 > 0x00 0x07 DATA CSB R 0x00 Data out<15:8> 0x08 DATA\_LSB R 0x00 Data out<7:0> 0x09 TEMP\_MSB R Temp out<15:8> 0x00 0x0A TEMP LSB R Temp out<7:0> 0x00

Table 4 Normal registers

#### Reg0x00

CMD

0x30

SDO active: 1: 4-wire SPI, 0: 3-wire SPI

RW

LSB first: 1: LSB first for SPI interface, 0: MSB first for SPI interface

Sleep\_time<3:0>

Soft\_reset: 1: Reset all the WF5805F registers (except 'margin'), automatically come

Sco

Measurement<2:0>

0x00

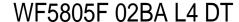
back to 0 after reset complete.

#### Reg0x01

**PartID:** OTP programmed 8 bits Part ID, corresponding to OTP register Reg0xA4. Read only from the address 0x01.

#### Reg0x02

**DRDY:** 1,indicates once conversion complete, and the output data is ready for reading.





**Error\_code:** When diagnostic function enabled, These bits stores the error information.

Error\_code[3]: VINP short to VDD

Error\_code[2]: VINP short to GND

Error\_code[1]: VINN short to VDD

Error code[0]: VINN short to GND

#### Reg0x06-Reg0x08

**Data\_out:** 24 bits ADC output data when 'raw\_data\_on' = 0 with an LSB equals to (1/64). 24 bits calibrated data when 'raw\_data\_on' = 1.

#### Reg0x09-Reg0x0a

**Temp out:** Temperature output with an LSB equals to (1/256)℃.

#### Reg0x30

**Sleep\_time<3:0>:** 0000:0ms, 0001:62.5ms, 0010:125ms ... 1111: 1s, only active during sleep mode conversion.

**Measurement\_control<1:0>:** 000b, indicate a single shot temperature signal conversion. 001b, indicate a single shot sensor signal conversion. 010b: indicate a combined conversion (once temperature conversion immediately followed by once sensor signal conversion). 011b: indicate a sleep mode conversion (periodically perform once combined conversion with an interval time of 'sleep\_time'), 100b: OTP programming mode, enter this mode to when programming OTP banks.

**Sco:** 1, Start of conversion, automatically come back to 0 after conversion ends (except sleep mode conversion).

### 4.2 OTP Registers

Table 5 OTP registers

Addr	Description	R/W	Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0	Default
0xA4	PartID	RW		PartID<7:0>			ОТР				
0xA5	Sys_config	RW		P_T_rati	ion<1:0>		Regul ator_ sel	Unipo lar	Raw _dat a_on	DIAG _on	ОТР
0xA6	P_config	RW	1′	b01	Ga	in_P<2:0	0>	09	SR_P<2:0	)>	ОТР
0xA7	T_config_1	RW	1′	b11	Ga	in_T<2:0	)>	09	SR_T<2:0	0>	ОТР



#### Reg0xA4

PartID: OTP programmed 8 bits Part ID, also can be read from address 0x01.

#### Reg0xA5

**P\_T\_ratio:** set how many sensor signal conversions performed after once temperature conversion during analog output mode. 00: 64 times, 01: 32 times, 10: 16 times, 11: once.

**Regulator sel:** 0: set the VEXT voltage to be 1.8V, 1: set the VEXT voltage to be 3.6V.

**Unipolar:** 0: ADC output in bipolar format, 1: ADC output in unipolar format. (Only take effect when 'raw\_data\_on' = 1)

**Raw\_data\_on:** 0: output calibrated data, 1: output ADC raw data. (Only take effect in single shot sensor signal conversion and single shot temperature conversion)

Diag on: 1, Enable diagnosis function.

#### Reg0xA6

Input Swap: Swap VINP and VINN inside the WF5805F.

**Gain\_P:** set the gain of the sensor signal conversion channel. 000: gain=1, 001: gain=2, 010: gain=4, 011: gain=8, 100: gain=16, 101: gain=32, 110: gain=64, 111: gain=128.

**OSR\_P:** set the over sampling ratio of the sensor signal conversion channel. 000:1024X, 001:2048X, 010:4096X, 011:8192X, 100:256X, 101:512X, 110:16384X, 111:32768X.

#### Reg0xA7

**Gain\_T:** set the gain of the temperature conversion channel. 000: gain=1, 001: gain=2, 010: gain=4, 011: gain=8, 100: gain=16, 101: gain=32, 110: gain=64, 111: gain=128.

**OSR\_T:** set the over sampling ratio of the temperature conversion channel. 000:1024X, 001:2048X, 010:4096X, 011:8192X, 100:256X, 101:512X, 110:16384X, 111:32768X.



## **5 SPI interface**

WF5805F provides both SPI and I2C interface for serial communication and 'CSB' pin is used to switch between these two protocols. Pulling 'CSB' pin low selects the SPI interface, leaving 'CSB' pin float or puling it high selects the I2C interface.

## **5.1 Interface Specification**

Table 6 SPI interface specification

Symbol	Parameter	Condition	Min	Max	Unit
f <sub>sclk</sub>	Clock frequency	Max load on SDIO or SDO=25pF		10	MHz
t <sub>sclk_l</sub>	SCLK low pulse		20		ns
t <sub>sclk_h</sub>	SCLK high pulse		20		
$T_{sdi\_setup}$	SDI setup time		20		ns
$T_{sdi\_hold}$	SDI hold time		20		ns
_	SDO/SDI output	Load = 25pF		30	ns
T <sub>sdo_od</sub>	delay	Load = 250pF		40	
T <sub>csb_setup</sub>	CSB setup time		20		ns
T <sub>csb_hold</sub>	CSB hold time		40		ns

The figure below shows the definition of the SPI timing given in table 6

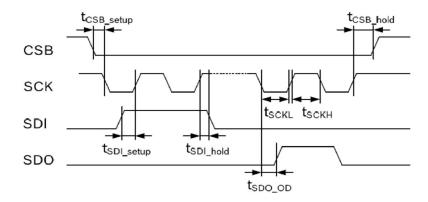


Figure 4 SPI timing diagram

The falling edge of CSB, in conjunction with the rising edge of SCLK, determines the start of framing. Once the



beginning of the frame has been determined, timing is straightforward. The first phase of the transfer is the instruction phase, which consists of 16 bits followed by data that can be of variable lengths in multiples of 8 bits. If the device is configured with CSB tied low, framing begins with the first rising edge of SCLK.

The instruction phase is the first 16 bits transmitted. As shown in Figure 5.2, the instruction phase is divided into a number of bit fields.

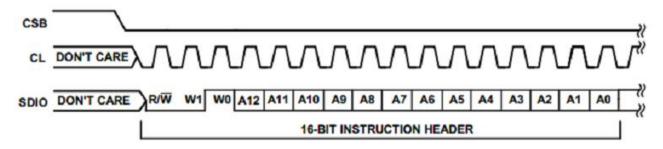


Figure 5 Instruction Phase Bit Filed

The first bit in the stream is the read/write indicator bit (R/W). When this bit is high, a read is being requested, otherwise indicates it is a write operation.

W1 and W0 represent the number of data bytes to transfer for either read or write (Table 5.2). If the number of bytes to transfer is three or less (00, 01, or 10), CSB can stall high on byte boundaries. Stalling on a nonbyte boundary terminates the communications cycle. If these bits are 11, data can be transferred until CSB transitions high. CSB is not allowed to stall during the streaming process.

The remaining 13 bits represent the starting address of the data sent. If more than one word is being sent, sequential addressing is used, starting with the one specified, and it either increments (LSB first) or decrements (MSB first) based on the mode setting.

W1:W0	Action	CSB stalling
00	1 byte of data can be transferred.	Optional
01	2 bytes of data can be transferred.	Optional
10	3 bytes of data can be transferred.	Optional
11	4 or more bytes of data can be transferred. CSB must be held	No
	low for entire sequence; otherwise, the cycle is terminated.	

Table 7 W1 and W0 settings

Data follows the instruction phase. The amount of data sent is determined by the word length (Bit W0 and Bit W1). This can be one or more bytes of data. All data is composed of 8-bit words.

Data can be sent in either MSB-first mode or LSB-first mode (by setting 'LSB\_first' bit). On power up, MSB-first mode is the default

This can be changed by programming the configuration register. In MSB-first mode, the serial exchange starts with the highest-order bit and ends with the LSB. In LSB-first mode, the order is reversed. (Figure 5.3)



## WF5805F 02BA L4 DT

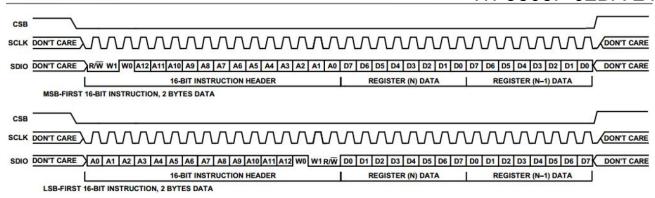


Figure 6 MSB First and LSB First Instruction and Data Phases

Register bit 'SDO\_active' is responsible for activating SDO on devices. If this bit is cleared, then SDO is inactive and read data is routed to the SDIO pin. If this bit is set, read data is placed on the SDO pin. The default for this bit is low, making SDO inactive.



## **6 I2C INTERFACE**

I2C bus uses SCL and SDA as signal lines. Both lines are connected to VDDIO externally via pull-up resistors so that they are pulled high when the bus is free. The I2C device address of WF5805F is shown below. The LSB bit of the 7bits device address is configured via SDO/ADDR pin.

Table 8 I2C Address

A7	A6	A5	A4	А3	A2	A1	W/R
1	1	0	1	1	0	SDO/ADDR	0/1

#### Electrical specification of the I2C interface pins

Symbol	Parameter	Condition	Min	Max	Unit
f <sub>scl</sub>	Clock frequency			400	kHz
t <sub>LOW</sub>	SCL low pulse		1.3		us
t <sub>HIGH</sub>	SCL high pulse		0.6		us
t <sub>SUDAT</sub>	SDA setup time		0.1		us
t <sub>HDDAT</sub>	SDA hold time		0.0		us
tsusta	Setup Time for a repeated start condition		0.6		us
t <sub>HDSTA</sub>	Hold time for a start condition		0.6		Us
t <sub>susto</sub>	Setup Time for a stop condition		0.6		Us
t <sub>BUF</sub>	Time before a new transmission can start		1.3		Us

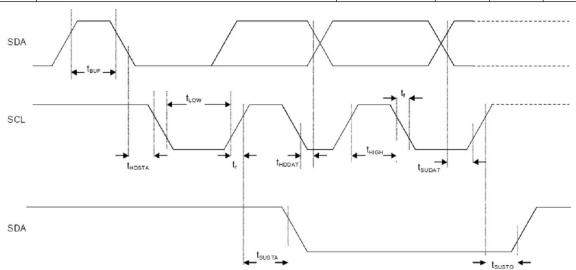


Figure 7 I2C Timing Diagram

The I2C interface protocol has special bus signal conditions. Start (S), stop (P) and binary data conditions are shown below. At start condition, SCL is high and SDA has a falling edge. Then the slave address is sent. After the 7 address bits, the direction control bit R/W selects the read or





write operation. When a slave device recognizes that it is being addressed, it should acknowledge by pulling SDA low in the ninth SCL (ACK) cycle.

At stop condition, SCL is also high, but SDA has a rising edge. Data must be held stable at SDA when SCL is high. Data can change value at SDA only when SCL is low.

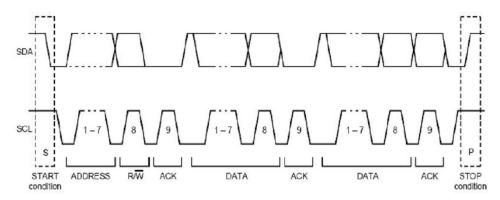
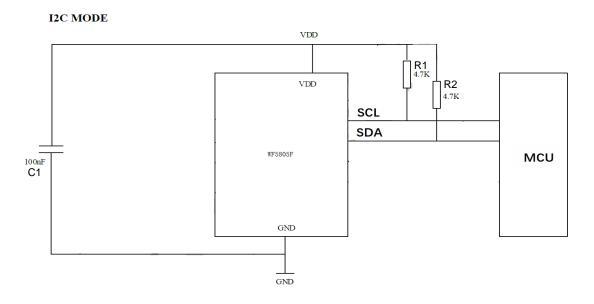


Figure 8 I2C Protocol



# 7 Connection diagram



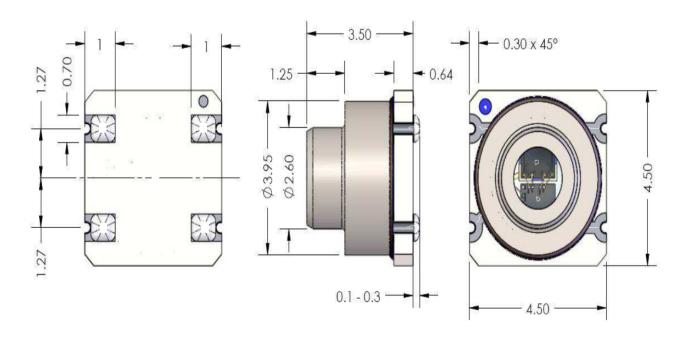
#### Notes:

- The recommended value for C1 is 100nF
- The value for the pull-up resistors R1, R2 should be based on the interface timing and the bus load; a normal value of R1 is  $4.7k\Omega$ , R2 is  $4.7k\Omega$ .

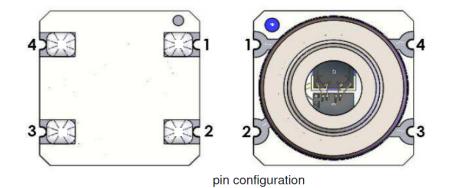


# 8 Package, reel and environment

## 8.1 Package Information



## 8.2 Pin Configuration



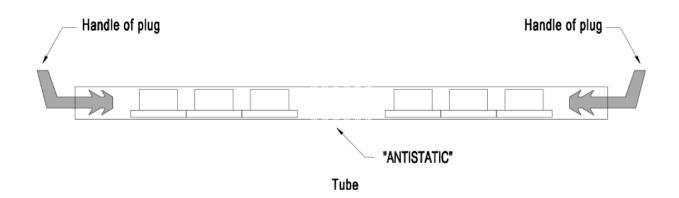
Pin	Name	Type	Function
1	VDD	Р	Positive supply voltage
2	SCL	1	Serial data Clock
3	SDA	Ю	I <sup>2</sup> C data IO
4	GND	Р	Ground

Notes:

Mechanical dimension is mm



## 8.3 Shipping Package







# 9 Soldering recommendation

The recommended soldering profile is shown in Figure 12, followed by a description of the profile features in Table 10.

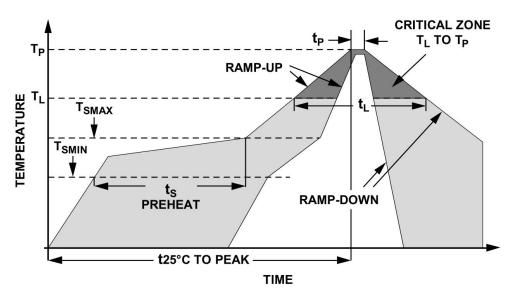


Figure 12 Recommended Soldering Profile

Table 10 Recommended Soldering Profile

Profile Feature	Pb-Free
Average ramp-up rate(TsMax to TP)	3°C/sec max.
Preheat:	
-Temperature Min.(TsMin)	150℃
-Temperature Max.(TxMax)	200℃
-Time.(TsMin to TsMax)(Ts)	60 sec to 180 sec
Time maintained above:	217℃
-Temperature(TL)	60 sec to 150 sec
-Time(tL)	ou sec to 130 sec
Peak temperature(TP)	260℃
Time within 5℃ of actual peak temperature(TP)2	20 sec to 40 sec
Ramp-down rate	4°C/sec max.
Time 25℃ to peak temperature	8 minutes max.